KURUKSHETRA UNIVERSITY KURUKSHETRA

Scheme of Examination and Syllabus for Under-Graduate Programme Subject: ELECTRONICS

Under Multiple Entry-Exit, Internship and CBCS-LOCF in accordance to NEP-2020 w.e.f. 2023-24 (in phased manner)

Scheme of Examination for Under-Graduate Programme Under Multiple Entry-Exit, Internship and CBCS-LOCF in accordance to NEP-2020 w.e.f. 2023-24 (in phased manner), Subject : Electronics

FIRST YEAR: SEMESTER-1										
Remarks	Course	Paper(s)	Nomenclature of Paper	Credits	Hours/ Week	Internal marks	External Marks	Total Marks	Exam Duration	
Scheme	CC-1 MCC-1	B23-ELE-	Electronic Devices and Network Analysis	3	3	20	50	70	3 hrs.	
Adt	4 credit	101	Practical	1	2	10	20	30	3 hrs.	
Scheme C only	MCC-2 4 credit B23-ELE- 102		Electronic Components, Measuring Instruments and Amplifiers	3	3	20	50	70	3 hrs.	
			Practical	1	2	10	20	30	3 hrs.	
Scheme	CC-M1	B23-ELE-	Basic Digital Electronics	1	1	10	20	30	3 hrs.	
Α	2 credit	103	Practical	1	2	5	15	20	3 hrs.	
Scheme	MDC-1	B23-ELE-	Electronics in Daily Life	2	2	15	35	50	3 hrs.	
A & C	3 credits	104	Practical	1	2	5	20	25	3 hrs.	
Scheme C only	CC-M1 4 credit		From Ava	ilable CC-M	11 of 4 cred	its as per NE	EP			
	AEC-1 2 credit		From Avai	lable AEC-1	of two crea	lits as per N	EP			
Scheme A & C	SEC-1 3 credit		From Available SEC-1 of three credits as per NEP							
	VAC-1 2 credit		From Available VAC-1 of two credits as per NEP							
FIRST YEAR: SEMESTER-2										
Remarks	Course	Paper(s)	Nomenclature of Paper	Credits	Hours/ Week	Internal marks	External Marks	Total Marks	Exam Duration	
Scheme	CC-2 MCC-3	B23-ELE-	Electronic Devices and Basic Digital Electronics	3	3	20	50	70	3 hrs.	
Aac	4 credit	201	Practical	1	2	10	20	30	3 hrs.	
Scheme C only	DSEC-2 4 credit	B23-ELE- 202	Power Devices & Multivibrators	3	3	20	50	70	3 hrs.	
· ·			Practical	1	2	10	20	30	3 hrs.	
Scheme	CC-M2	B23-ELE-	Basic Electronic components & Devices	1	1	10	20	30	3 hrs.	
A only	2 credit	203	Practical	1	2	5	15	20	3 hrs.	
Scheme A & C	MDC-2 3 credits	B23-ELE- 204	Understanding of Mobiles and Computer Systems	2	2	15	35	50	3 hrs.	
			Practical	1	2	5	20	25	3 hrs.	
Scheme C only	CC-M2 4 credit		From Ava	ilable CC-M	12 of 4 cred	its as per NE	EP			
	AEC-2 2 credit		From Avai	lable AEC-2	of two crea	dits as per N	EP			
Scheme A & C	SEC-2 3 credit		From Avail	able SEC-2	of three cre	dits as per N	EP			
	VAC-2 2 credit		From Avail	lable VAC-2	of two cree	dits as per N	EP			
Internship of 4 credits of 4-6 weeks duration after 2 nd Semester										

SECOND YEAR: SEMESTER-3									
Remarks	Course	Paper(s)	Credits	Hours/ Week	Internal marks	External Marks	Total Marks	Exam Duration	
Scheme	CC-3 MCC-4	B23-ELE-	Combinational & Sequential Circuits	3	3	20	50	70	3 hrs.
Α, Βα C	4 credit	501	Practical	1	2	10	20	30	3 hrs.
Scheme	MCC-5	B23-ELE-	Digital Electronics	3	3	20	50	70	3 hrs.
B & C	4 credit	302	Practical	1	2	10	20	30	3 hrs.
Scheme	MDC-3	B23-ELE-	Electronics in Smart World	2	2	15	35	50	3 hrs.
A, B & C	3 credits	303	Practical	1	2	5	20	25	3 hrs.
Scheme A & C	CC-M3 4 credits		From Avai	lable CC-N	13 of 4 credi	ts as per NE	P		
Calara C	CC-M3								
Scheme B only	(V) 4 credits		From Availa	ble CC-M3	(V) of 4 cre	dits as per N	EP		
Scheme	AEC-3 2 credit		From Avail	able AEC-3	3 of two cred	lits as per NI	EP		
A, B & C SEC-3 3 credit From Available SEC-3 of three credits as					lits as per N	NEP			
Scheme C only	VAC-3 2 credits		From Available VAC-3 of two credits as per NEP						
Scheme B only	MCC-3		MCC-2 FROM SCHEME C OF FIRST SEMESTER						
		SECOND YEAR: SEMESTER-4							
Remarks	Course	Paper(s)	Nomenclature of Paper	Credits	Hours/ Week	Internal marks	External Marks	Total Marks	Exam Duration
Scheme A, B & C	CC-4 MCC-6	B23-ELE- 401	Operational Amplifier & Sinusoidal Oscillators	3	3	20	50	70	3 hrs.
	4 credit		Practical	1	2	10	20	30	3 hrs.
Scheme	4 credit	B23-ELE- 402	IC Fabrication Technology	3	3	20	50	70	3 hrs.
B&C			D (* 1						
Schomo			Practical	1	2	10	20	30	3 hrs.
	MCC-8	B23-ELE-	Electronic Communication	1 3	23	10 20	20 50	30 70	3 hrs. 3 hrs.
B & C	MCC-8 4 credit	B23-ELE- 403	Practical Electronic Communication Practical	1 3 1	2 3 2	10 20 10	20 50 20	30 70 30	3 hrs. 3 hrs. 3 hrs.
B & C	MCC-8 4 credit	B23-ELE- 403 B23-ELE-	Practical Electronic Communication Practical Optical Fiber Communication	1 3 1 3	2 3 2 3	10 20 10 20	20 50 20 50	30 70 30 70	3 hrs. 3 hrs. 3 hrs. 3 hrs.
B & C Scheme	MCC-8 4 credit DSE-1 4 credit	B23-ELE- 403 B23-ELE- 404	Practical Electronic Communication Practical Optical Fiber Communication Practical	1 3 1 3 1	2 3 2 3 2	10 20 10 20 10	20 50 20 50 20	30 70 30 70 30	3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs.
Scheme B & C Scheme B & C	MCC-8 4 credit DSE-1 4 credit Select one option	B23-ELE- 403 B23-ELE- 404 B23-ELE-	Practical Electronic Communication Practical Optical Fiber Communication Practical Wireless & Mobile Communication	1 3 1 3 1 3	2 3 2 3 2 3 3	10 20 10 20 10 20 10 20	20 50 20 50 20 50	30 70 30 70 30 70 30 70 30 70	3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs.
Scheme B & C Scheme B & C	MCC-8 4 credit DSE-1 4 credit Select one option	B23-ELE- 403 B23-ELE- 404 B23-ELE- 405	Practical Electronic Communication Practical Optical Fiber Communication Practical Wireless & Mobile Communication Practical	1 3 1 3 1 3 1	2 3 2 3 2 3 2 3 2	10 20 10 20 10 20 10 20 10 20 10 20 10 20 10	20 50 20 50 20 50 20 20	30 70 30 70 30 70 30 70 30 70 30 70 30 70 30	3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs.
Scheme B & C Scheme Scheme	MCC-8 4 credit DSE-1 4 credit Select one option CC-M4 (V) 4 credits	B23-ELE- 403 B23-ELE- 404 B23-ELE- 405	Practical Electronic Communication Practical Optical Fiber Communication Practical Wireless & Mobile Communication Practical From Availa	1 3 1 3 1 3 1 ble CC-M4	2 3 2 3 2 3 2 (V) of 4 crea	10 20 10 20 10 20 10 dits as per N	20 50 20 50 20 50 20 EP	30 70 30 70 30 70 30 70 30 70 30 70 30 70 30	3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs.
Scheme B & C Scheme B & C Scheme A, B & C	MCC-8 4 credit DSE-1 4 credit Select one option CC-M4 (V) 4 credits AEC-4 2 credit	B23-ELE- 403 B23-ELE- 404 B23-ELE- 405	Practical Electronic Communication Practical Optical Fiber Communication Practical Wireless & Mobile Communication Practical From Availa	1 3 1 3 1 3 1 ble CC-M4 able AEC-3	2 3 2 3 2 3 2 (V) of 4 cree 3 of two cred	10 20 10 20 10 20 10 dits as per N	20 50 20 50 20 50 20 EP EP	30 70 30 70 30 70 30 70 30 70 30 70 30 70 30 70 30 70 30	3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs.
Scheme B & C Scheme A, B & C Scheme C only	MCC-8 4 credit DSE-1 4 credit Select one option CC-M4 (V) 4 credits AEC-4 2 credit VAC-4 2 credits	B23-ELE- 403 B23-ELE- 404 B23-ELE- 405	Practical Electronic Communication Practical Optical Fiber Communication Practical Wireless & Mobile Communication Practical From Availa From Availa	1 3 1 3 1 3 1 1 1 1 1 1 1 1 1 1 1 1 1 1	2 3 2 3 2 3 2 (V) of 4 creations 3 of two creations 4 of two creations	10 20 10 20 10 20 10 20 10 20 10 20 10 20 10 20 10 dits as per N lits as per NI lits as per NI	20 50 20 50 20 50 20 EP EP EP	30 70 30 70 30 70 30 70 30 70 30 70 30 70 30 70 30	3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs.
Scheme B & C Scheme A, B & C Scheme C only Scheme A & B	MCC-8 4 credit DSE-1 4 credit Select one option CC-M4 (V) 4 credits AEC-4 2 credit VAC-4 2 credits VAC-3 2 credits	B23-ELE- 403 B23-ELE- 404 B23-ELE- 405	Practical Electronic Communication Optical Fiber Communication Practical Wireless & Mobile Communication Practical From Availa From Availa From Availa From Availa	1 3 1 3 1 3 1 3 1 3 1 3 1 3 1 3 1 3 1 able CC-M4 able AEC-3 able VAC-4 able VAC-3	2 3 2 3 2 3 2 (V) of 4 created 3 of two created 3 of two created 3 of two created	10 20 10 20 10 20 10 20 10 20 10 20 10 20 10 dits as per N lits as per NI lits as per NI lits as per NI	20 50 20 50 20 50 20 EP EP EP EP	30 70 30 70 30 70 30 70 30 70 30	3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs. 3 hrs.

THIRD YEAR: SEMESTER-5										
Remarks	Course	Paper(s)	Nomenclature of Paper	Credits	Hours/ Week	Internal marks	External Marks	Total Marks	Exam Duration	
Scheme	CC-5	B23-ELE-	Transducers and Sensors	3	3	20	50	70	3 hrs.	
A, B & C	MCC-9 501		Practical	1	2	10	20	30	3 hrs.	
Scheme	MCC-10	B23-ELE-	Digital Signal Processing	3	3	20	50	70	3 hrs.	
B & C	4 credit	502	Practical	1	2	10	20	30	3 hrs.	
Scheme	DSE-2 4 credit	B23-ELE- 503	Microprocessor Architecture and Programming with 8085	3	3	20	50	70	3 hrs.	
B & C	Select one		Practical	1	2	10	20	30	3 hrs.	
	Option	B23-ELE-	Optoelectronic Devices	3	3	20	50	/0	3 hrs.	
		504 D22 ELE	Practical	1	2	10	20	30	3 hrs.	
Sahama	DSE-3	505	Practical	1	2	10	20	30	3 hrs	
B & C	Select one	B23-ELE-	Embedded Systems	3	3	20	50	70	3 hrs	
	Option	506	Practical	1	2	10	20	30	3 hrs.	
Scheme	CC-M5 (V)		E 4 '1	11 00 10	-	1			•	
A & C	4 credits		From Availa	able CC-M5	(V) of 4 cre	dits as per N	EP			
Scheme A, B & C	Internship 4 credits		Inter	nship#4 cre	dit after 4 th s	semester				
	THIRD YEAR: SEMESTER-6									
Remarks	Course	Paper(s)	Nomenclature of Paper	Credits	Hours/ Week	Internal marks	External Marks	Total Marks	Exam Duration	
	CC (Microcontroller 8051 and							
Scheme A, B & C	MCC-11 4 credit	MCC-11 B2 4 credit	B23-ELE- 601	its Interfacing	3	3	20	50	70	3 hrs.
~ -	MGG 10		Practical	1	2	10	20	30	3 hrs.	
Scheme B & C	MCC-12 4 credit	B23-ELE- 602	Basic Electrical Engineering & Skills	3	3	20	50	70	3 hrs.	
			Practical	1	2	10	20	30	3 hrs.	
Scheme	DSE-4 4 credit Select one	DSE-4	B23-ELE- 603	Interfacing Peripheral Devices and Applications of 8085	3	3	20	50	70	3 hrs.
B & C		nt one	Practical	1	2	10	20	30	3 hrs.	
	Option	btion B23-ELE-	Verilog and FPGA based System Design	3	3	20	50	70	3 hrs.	
		004	Practical	1	2	10	20	30	3 hrs.	
Gabarra	DSE-5	B23-ELE-	Introduction to C and its programming	3	3	20	50	70	3 hrs.	
Scheme B & C	4 credit	005	Practical	1	2	10	20	30	3 hrs.	
Dae	Select one Option	B23-ELE-	Modern communication systems	3	3	20	50	70	3 hrs.	
		000	Practical	1	2	10	20	30	3 hrs.	
Scheme A only	CC-M6 4 credits		From Ava	ilable CC-N	16 of 4 credi	ts as per NE	Р			
Scheme A only	CC-M7(V) 4 credits		From Availa	able CC-M7	(V) of 4 cre	dits as per N	EP			
Scheme B only	CC-M5(V) 4 credits		From Availa	ble CC-M5	(V) of 4 cre	edits as per I	NEP			
Scheme C cmby	CC-M6(V)		From Availa	ble CC-M6	(V) of 4 cre	dits as per l	NEP			
Scheme	4 creats SEC-4		From Avai	lable SEC-4	of two cred	its as per NF	EP			
C only	2 credit		from Available SEC-4 of two credits as per NEP							

FOURTH YEAR: SEMESTER-7 (FOR HONOURS/HONOURS WITH RESEARCH IN ELECTRONICS)									
Remarks	Course	Paper(s)	r(s) Nomenclature of C Paper		Hours/ Week	Internal marks	External Marks	Total Marks	Exam Duration
	CC-H1 4 credit	B23-ELE- 701	Digital Circuits and System Design	4	4	30	70	100	3 hrs.
for Honours in Electronics/	CC-H2 4 credit	B23-ELE- 702	MOS Analog Circuits	4	4	30	70	100	3 hrs.
Honours with	CC-H3 4 credit	B23-ELE- 703	Instrumentation and Control Systems	4	4	30	70	100	3 hrs.
Research in Electronics	DSE-H1 4 credit Select	B23-ELE- 704	Optical Fiber Communication	4	4	30	70	100	3 hrs.
(For Scheme B & C)	one Option	B23-ELE- 705	CAD Tools for VLSI	4	4	30	70	100	3 hrs.
	PC-H1 4 credit	B23-ELE- 706	Practical Based on B23-ELE-701 TO 704/705	4	8	30	70	100	6 hrs.
	CC-HM1 4 credit		From Avai	lable Minor	of 4 credit	s as per NEI)		
		S	SEMESTER-8 (FOR HONOU	JRS IN EL	ECTRON	ICS)			
Remarks	Course	Paper(s)	Nomenclature of Paper	Credits	Hours/ Week	Internal marks	External Marks	Total Marks	Exam Duration
	CC-H4 4 credit	B23-ELE- 801	Microwave devices and systems	4	4	30	70	100	3 hrs.
Honours	CC-H5 4 credit	B23-ELE- 802	MOS Digital Circuits	4	4	30	70	100	3 hrs.
in Electronics	CC-H6 4 credit	B23-ELE- 803	Device Models and Circuit Simulation	4	4	30	70	100	3 hrs.
(For	DSE-H2 4 credit	B23-ELE- 804	Semiconductor Material & Device Characterization	4	4	30	70	100	3 hrs.
Scheme B & C)	Select one optionB23-ELE- 805Digital Communicatio		Digital Communication	4	4	30	70	100	3 hrs.
	PC-H2 4 credit	B23-ELE- 806	Practical Based on B23-ELE-801 TO 804/805	4	8	30	70	100	6 hrs.
	CC-HM2 4 credit		From Avai	lable Minor	of 4 credit	s as per NEI)		
		OR SEMEST	ER-8 (FOR HONOURS WI	TH RESEA	RCH IN I	ELECTRON	NICS)		
Remarks	Course	Paper(s)	Nomenclature of Paper	Credits	Hours/ Week	Internal marks	External Marks	Total Marks	Exam Duration
Honours	CC-H4 4 credit	B23-ELE- 801	Microwave devices and systems	4	4	30	70	100	3 hrs.
with Research in Electronics	CC-H5 4 credit	B23-ELE- 802	MOS Digital Circuits	4	4	30	70	100	3 hrs.
Project/ (For Dissertat B23-ELE- Scheme B ion & C) 12 credit		Project/Dissertation	8+4	-	-	300	300	-	
	CC-HM2 4 credit		From Avai	lable Minor	of 4 credit	s as per NEI			

Session: 2023-24						
Part A - Introduction						
Subject		ELECTRONICS				
Semester		FIRST				
Name of the Course		Electronic Devi	ces and Network Anal	ysis		
Course Code		B23-ELE-101				
Course Type: (CC/MCC/MDC/CC- M/DSEC/VOC/DSE/PC/AEC/VAC)		CC-1				
	,	MCC-1				
Level of the course	100-199					
Pre-requisite for the cour	Physics as a Subject at 4.0 Level (Class XII)					
Course Learning Outcomes (CLO): After completing this course, the learner will be able to: understand the construction, working & applications of vase semiconductor diodes Learn about the use of filters in rectifiers and about Bipola Junction Transistor. understand the concept of various network circuits and its understand the conversion of one network to another present the experimental results and conclusions by having 				able to: ications of various 1 about Bipolar ircuits and its uses another ions by having		
Credits	The	eory	Practical	Total		
		3	1	4		
Contact Hours	۷	45	30	75		
Max. Marks: 100 (70 The Internal Assessment Marks: 2 End Term Exam Marks: 50 T	ical) Practical actical	1) Exam Time: 3 Hours each for Theory & actical Practical				
	Part B- C	ontents of the	Course			
Instructions for Paper- Setter 1. Nine questions will be set in all. All questions will carry equal marks. 2. Ouestion No 1 which will be short answer type covering the entire syllabus will be						

2. Question No. 1, which will be short answer type covering the entire syllabus, will be compulsory. The remaining eight questions will be set unit wise selecting two questions from each Unit I to IV. The candidate will be required to attempt question No. 1 and four more questions selecting one question from each unit.

Unit	Topics	Contact Hours						
Ι	Semiconductors Devices & applications: - Overview of Semiconductors, Junction diode and its characteristics, Zener diode, Voltage Regulation using Zener Diode, shunt and series clipping circuit, clamping circuit. Rectifiers: - HWR, FWR, Bridge FWR, calculation of rectifier parameters.	11						
П	 Filter circuits: L, C, LC (Calculation of ripple factor for capacitor filter only), Voltage multiplier Circuit. Bipolar Junction Transistor: - Potential curves in unbiased and biased transistor, Transistor current components, Static Characteristics of CB & CE configuration, active, cut off and saturation regions. Transistor current gains (Alpha, Beta, and Gama), Transistor as an Amplifier 	12						
III	 Network Theorems: - Superposition theorem, Thevenin's Theorem, Norton's Theorem, Maximum Power Transfer Theorem, Millman's Theorem, examples and problems of each topic. Two–port Network: -Open Circuit Impedance(Z) Parameters, Short Circuit Admittance (Y) Parameters, Transmission (ABCD) Parameters, Inverse Transmission (A'B'C'D') Parameters, Hybrid(H) Parameters, Inverse Hybrid(g) Parameters 	11						
IV	Conversion of Parameters, Dependent sources (CCCS, VCVS, VCCS, CCVS), Inter Connection of Two – Port Networks, T and π Representation, Terminated Two-Port Networks, Lattice Networks, Image Parameters	11						
V*	 Note: A candidate is required to perform minimum 6 experiments out of the list provided during course of study in this semester. 1. To study the V-I characteristics of PN junction diode. 2. To study the Zener diode as voltage regulator. 3. To study HWR and FWR and measurement of ripple factor with and without C filter. 4. To study diode as shunt clipping clement. 5. To study diode as clamping element. 6. Study of Input and output CB characteristics . 7. Study of CE Input and Output characteristics 8. Measurement of voltageand Time period using CRO. 9. Measurement of resistance value using colour codes and multimeter. Also design and verify the potential divider arrangement using resistances. 10. To verify maximum power transfer theorem for DC network. 	30						
	Suggested Evaluation Methods							

 Internal Assessment: ➤ Theory 20 Marks Class Participation: 5 Marks Seminar/presentation/assignment/quiz/class test etc.: 5 Marks Mid-Term Exam: 10 Marks ➤ Practicum 10 Marks Class Participation: Seminar/Demonstration/Viva-voce/Lab records etc.: 10 Marks 	End Term Examination: 50 Marks 20 Marks					
• Mid-Term Exam:						
Part C-Learning Resources						
 Recommended Books/e-resources/LMS: 1. Integrated Electronics by Millman and Halkias. 2. Basic Electronics and Linear Circuits by NN Bhargava, DC Kulshresl 3. Electronics Devices and Circuit by Allen Mottershead 4. Circuits and Networks by A. Sudhakar, Shyammohan 5. Network Analysis, Publication Khanna by G.K. Mithal 6. Network Analysis, Publication Pearson India by M.E. Van Valkenburg 	ntha (TTTI) g					

	Ses	sion: 2023-24			
	Part	A - Introductior	1		
Subject		ELECTRONICS			
Semester		FIRST			
Name of the Course	Electronic Com Amplifiers	Electronic Components, Measuring Instruments and Amplifiers			
Course Code		B23-ELE-102			
Course Type: (CC/MCC/MDC/CC- M/DSEC/VOC/DSE/PC/AEC/VAC)		MCC-2			
Level of the course		100-199			
Pre-requisite for the cour	rse (if any)	Physics as a Subject at 4.0 Level (Class XII)			
Course Learning Outcomes (CLO): After completing this course, the learner will be able to: 1. Learn about Passive components and their use 2. Understand the concept and use of different me instruments. 3. Understand the basics of Bipolar Junction Transistors 4. Understand the construction and working of different ar				e able to: use different measuring ransistors of different amplifiers work	
Credits	The	eory	Practical	Total	
		3	1	4	
Contact Hours	2	15	30	75	
Max. Marks: 100 (70 The Internal Assessment Marks: 50 T End Term Exam Marks: 50 T	ical) Practical actical	cal Exam Time: 3 Hours each for Theory & Practical			
Part B- Contents of the Course					
Instructions for Paper- Setter1. Nine questions will be set in all. All questions will carry equal marks.2. Question No. 1, which will be short answer type covering the entire syllabus, will be					

 Question No. 1, which will be short answer type covering the entire syllabus, will be compulsory. The remaining eight questions will be set unit wise selecting two questions from each Unit I to IV. The candidate will be required to attempt question No. 1 and four more questions selecting one question from each unit.

Unit	Topics	Contact Hours						
Ι	PassiveComponents:Resistors,Capacitors,Inductors,Transformers, Relays, Fuses (their types & applications).Introductions).Introductions).Introduction to Semiconductors:Energy Band Diagram, Conductors,Semiconductors, Insulators, Intrinsic and Extrinsic Semiconductors(P&N), currents in semiconductors, Diffusion Junction, Depletion	11						
II	Layer, Barrier Potential. Measuring Instruments: Regulated power supply, Analogue Multimeter, Digital Multimeter, Cathode Ray Oscilloscope, Function Generator (functional block diagram, basic working principle, measuring quantities). Zener diode regulator: circuit diagram and explanation for load and line regulation, disadvantages of Zener diode regulator.	11						
III	Bipolar Junction Transistor: Basic working principle, Input and Output Characteristics of CB & CE configurations, Biasing, Operating point, Load line, thermal runaway, stability and stability factor, Stabilization of Operating Point, Collector to Base bias, Voltage Divider bias and Emitter bias (+VCC &-VEE bias), circuit diagrams and their working.	12						
IV	Amplifiers: Classification of amplifiers, Class-A, B, AB and C Amplifiers, Cascading of Amplifiers, RC Coupled amplifiers. Properties of amplifiers (distortion, noise, thermal noise, shot noise, noise figure). Feedback in Amplifiers: Feedback concept, transfer gain with feedback, Effect of Negative Feedback on amplifiers performance. Transistor as a switch (circuit and working), Darlington pair and its applications.	11						
V*	 Note: A candidate is required to perform minimum 6 experiments out of the list provided during course of study in this semester. 1. Identification and study of Electronics Components. 2. Understanding the use of Function generator and draw the different wave shapes by connecting it with CRO. 3. Understand the use of Multimeter by measuring resistance, capacitance, voltage, frequency, transistor type etc. 4. Measurement of voltage. Time period and phase-shift using CRO. 5. Study of fixed bias arrangement for transistor. 6. Study of Voltage divider bias arrangement for transistor. 7. Study of Collector to base bias arrangement for transistor. 8. Study multi stage R-C coupled amplifier & to determine frequency response & gain 9. Find the gain (i) Class A. Amplifier (ii) Class B. Amplifier (iii) Class C Amplifier. 10. Verify the operation of transistor as a switch and draw the waveform. 	30						
	Suggested Evaluation Methods							

Internal Assessment: ➤ Theory 20 Marks • Class Participation: 5 Marks	End Term Examination: 50 Marks				
 Seminar/presentation/assignment/quiz/class test etc.: 5 Marks Mid-Term Exam: 10 Marks Practicum 10 Marks Class Participation: Seminar/Demonstration/Viva-voce/Lab records etc.: 10 Marks Mid-Term Exam: 	20 Marks				
Part C-Learning Resources					
 Recommended Books/e-resources/LMS: 1. Integrated Electronics by Millman and Halkias. 2. Basic Electronics and Linear Circuits by NN Bhargava, DC Kulshreshtha (TTTI) 3. Electronics Devices and Circuit by Allen Mottershead 4. Electronic Devices & Circuits by Sanjeev Gupta , Dhanpat Rai Publications 					

	Se	ession: 2023-24				
	Part	A - Introductio	n			
Subject		ELECTRONICS				
Semester		FIRST				
Name of the Course	Basic Digital Ele	ectronics				
Course Code		B23-ELE-103				
Course Type: (CC/MCC/M M/DSEC/VOC/DSE/PC/AI	CC-M1					
Level of the course		100-199				
Pre-requisite for the cour	se (if any)	Physics as a Subject at 4.0 Level (Class XII)				
Course Learning Outcomes (CLO):	 After completing this course, the learner will be able to: To understand the basics of various Number systems and their conversions To understand the basics of Boolean algebra and its theorems To understand the concept and basics of different logic gates To understand the concept and minimization techniques using K-maps To learn and understand the use of various electronic components and equipment's used for analysis of basic digital electronic relations 					
Credits	The	eory	Practical	Total		
		1	1	2		
Contact Hours	1	15	30	45		
Max. Marks: 50 (30 Th Internal Assessment Marks End Term Exam Marks: 20	eory + 20 Prac s: 10 Theory + 0 Theory + 15 1	tical) 5 Practical Practical	Exam Time: 3 Ho Practical	ırs each for Theory &		
Part B- Contents of the Course						
 Instructions for Paper- Setter Nine questions will be set in all. All questions will carry equal marks. Question No. 1, which will be short answer type covering the entire syllabus, will be compulsory. The remaining eight questions will be set unit wise selecting two questions from each Unit I to IV. The candidate will be required to attempt question No. 1 and four more questions selecting one question from each unit. 						

Unit	Topics	Contact Hours
Ι	Number Systems: Introduction to Decimal, Binary, Octal, Hexadecimal Number Systems and their inter-conversions; BCD codes, Excess-3 codes, Gray codes, code conversions, binary arithmetic (addition, Subtraction, multiplication, division), 1's and 2's compliments and 9's and 10's compliments.	3
II	Boolean Algebra: Postulates & theorems of Boolean algebra, Duality Principle, De-Morgan's Theorem.	4
III	Logic Gates: Positive and Negative Logic, Basic Logic Gates: AND, OR, NOT (symbol, truth-table, circuit diagram, working); NAND, NOR, EX-OR, EX-NOR (symbol, truth table).	4
IV	Minimization Techniques: Reduction of Boolean expressions using Boolean Identities, SOP and POS form of Boolean functions, Karnaugh Map simplifications, implementations of SOP and POS form using NAND and NOR gates.	4
V*	 Note: A candidate is required to perform minimum 4 experiments out of the list provided during course of study in this semester. Design of basis logic gates using discrete components. Study of different type of digital IC's :(functions, pin diagram, block diagram of various Digital ICs etc.). Data Sheet Analysis of Digital ICs (Quote the data sheet of any two digital ICs in Laboratory File). Realization of Boolean Identities on Digital Trainer Kit. Digital trainer using AOI. Digital trainer using NAND gates. Realization of K-map expression on Digital Trainer Kit. 	30
	Suggested Evaluation Methods	
Intern ≻ T • • • • • • •	End Term Examination: 20 Marks 15 Marks	
•	Mid-Term Exam:	
Deer	Part U-Learning Kesources	
1. Dig 2. Dig	ital Electronics by R.P. Jain ital Computer Electronics by A. P. Malvino	

Session: 2023-24						
Part A - Introduction						
Subject		ELECTRONICS				
Semester		FIRST				
Name of the Course		Electronics in E	Daily Life			
Course Code		B23-ELE-104				
Course Type: (CC/MCC/MDC/CC- M/DSEC/VOC/DSE/PC/AEC/VAC)		MDC-1				
Level of the course		100-199				
Pre-requisite for the cour	se (if any)	Any Arts, Commerce Subject at 4.0 Level (Class XII)				
Course Learning Outcomes (CLO): After completing this course, the learner will be able to: Understand about various electronic components Learn about the use of AC and DC voltages and transformers etc Understand the concept of assembling and disassembling of various home appliances. Learn the concept and importance of earthing To get practical exposure of various electronics components and appliances Instant appliances						
Credits	The	eory	Practical	Total		
		2	1	3		
Contact Hours	30		30	60		
Max. Marks: 75 (50 Theo Internal Assessment Marks: End Term Exam Marks: 35 T	eal) Exam Time: 3 Hours each for Theory & Practical Practical					
Part B- Contents of the Course						
 Instructions for Paper- Setter Nine questions will be set in all. All questions will carry equal marks. Question No. 1, which will be short answer type covering the entire syllabus, will be compulsory. The remaining eight questions will be set unit wise selecting two questions from 						

questions selecting one question from each unit.3. Medium of examination may be Hindi/English.

each Unit I to IV. The candidate will be required to attempt question No. 1 and four more

Unit	Topics	Contact Hours			
Ι	Introduction to basic Electronics components and Devices: Resistor, Color code, Inductor, Capacitor, basic Potentiometer circuit, Multiple range Potentiometer	7			
	Classification of Instruments, Analog and Digital Mode of operations, Basics of CRO, Multimeter				
П	AC - DC Voltage, Domestic Electric supply, Transformer, Power consumption, wire, electric tester, clamp meter, Fuse, circuit breaker, Inverter, Electric consumption meter reading, BEE rating, Soldering techniques, LED, Display HD, Full HD and UHD.	8			
III	Repair and Maintenance of Home Appliances(Basic idea of Internal Circuit and working): Inverters and UPS, Switch Mode Power Supply, washing Machine , Electric Iron, Microwave Oven, Rice Cooker	9			
IV	Measurement of Earth Resistance: Necessity of Earth Electrode, Necessity of measurement of Earth Electrode, Factors effecting Earth Electrodes, Methods of measuring Earth Resistance	6			
V*	 Note: A candidate is required to perform minimum 4 experiments out of the list provided during course of study in this semester. 1. Measurement of alternating voltage using multimeter. 2. Measurement of voltage and Time period and using CRO. 3. Measurement of resistance value using colour codes and multimeter. 4. Design and verify the potential divider arrangement using resistances. 5. Testing of wire, measuring voltage, current and frequency using multimeter 6. Demonstrate soldering of basic electronics components using soldering iron. 7. Understanding the role of transformer. 	30			
	Suggested Evaluation Methods	Γ			
Interr ≻ T • • • • •	heory 15 Marks Class Participation: 4 Marks Seminar/presentation/assignment/quiz/class test etc.: 4 Marks Mid-Term Exam: 7 Marks racticum 5 Marks Class Participation: Seminar/Demonstration/Viva-voce/Lab records etc.: 5 Marks Mid-Term Exam:	End Term Examination: 35 Marks 20 Marks			
Part C-Learning Resources					

- 1. A course in Electrical and Electronic Measurements and Instrumentation by A K Sawhney.
- 2. Electronics Instrumentation and Measurement Techniques by W D Cooper
- 3. Handbook of Repair and Maintenance of Domestic Electronics Appliances, Shashi Bhushan Sinha, BPB Publications
- 4. Getting Down to Earth: A practical guide to earth resistance testing, Megger

Session: 2023-24					
Part A - Introduction					
Subject		ELECTRONICS			
Semester		SECOND			
Name of the Course		Electronic Devi	ces and Basic Digital E	ectronics	
Course Code		B23-ELE-201			
Course Type: (CC/MCC/MDC/CC- M/DSEC/VOC/DSE/PC/AEC/VAC)		CC-2 MCC-3			
Level of the course	100-199				
Pre-requisite for the cour	Electronics as a Subject (CC-1)				
Course Learning Outcomes (CLO):	 After completing this course, the learner will be able to: Student will be able 1. To describe the basic Biasing Techniques. 2. To understand the basics of Field effect transistors 3. To learn about the number systems, conversions and K-map's 4. To understand the basics of Logic gates and Families 5. Hands-on practice of the analog and Digital based experiments 				
Credits	The	eory	Practical	Total	
	3 1 4				
Contact Hours	2	45	30	75	
Max. Marks:100 (70 Theory + 30 Practical)Exam Time: 3 Hours each for TheorInternal Assessment Marks:20 Theory + 10 PracticalPracticalEnd Term Exam Marks:50 Theory + 20 PracticalPractical			s each for Theory &		
Part B- Contents of the Course					
Instructions for Paper- Setter					

Nine questions will be set in all. All questions will carry equal marks.
 Question No. 1, which will be short answer type covering the entire syllabus, will be compulsory. The remaining eight questions will be set unit wise selecting two questions from each Unit I to IV. The candidate will be required to attempt question No. 1 and four more questions selecting one question from each unit.

Unit	Topics	Contact Hours
Ι	Transistor Biasing Techniques: -Why Bias a Transistor, Selection of Operating Point, need for Bias Stabilization, Requirement of a Biasing Circuit, Different Biasing Circuits: Bias Circuit with Emitter Resistor, Voltage Divider Biasing Circuit, Emitter-Bias Circuit, Gain of a multi-stage amplifier.	12
II	Field Effect Transistor: - Junctions Field Effect Transistor, Qualitative Description of JFET, Drain and transfer characteristics of JFET, FET small signal low frequency model, CS & CD low frequency model, MOSFET -Depletion and enhancement and their drain & transfer characteristics, CMOS (Basic idea).	12
III	Number Systems: - Binary, Octal, Hexadecimal number system and base conversions, Binary Arithmetic operations, 1's and 2's complement representation and their arithmetic, Binary codes-BCD, Gray, Error detecting and correcting codes, BCD addition, Boolean Algebra: Postulates, Duality Principle, De Morgan's Law, Simplification of Boolean Identities, Standard SOP & POS Forms, Simplification using K-map (upto 4 variables), don't care condition, implementation of SOP & POS form using NAND and NOR Gate.	11
IV	 Logic Gates: Positive and Negative logic level, Logic Gates: AND, OR, NOT, XOR, XNOR, NOR, NAND (Definition, Symbols & Truth table). Logic families: Unipolar & Bipolar Logic families, characteristics of Digital IC's (fan in, fan out, propagation delay. Noise Margin), RTL (NOR), DTL (NAND), TTL (NAND), CMOS Logic gate (NAND, NOR). 	10
V*	 Note: A candidate is required to perform minimum 6 experiments out of the list provided during course of study in this semester. 1. Study of fixed bias arrangement for transistors. 2. Study of voltage divider biasing arrangement for transistors. 3. Study of two stage R-C coupled transistor amplifier. 4. Study of JFET characteristics. 5. Study of different type of digital IC's :(functions, pin diagram, block diagram of various Digital ICs etc.). 6. Design of basis logic gates using discrete components. 7. Study of TTL NAND gate. 8. Study of TTL NAND gate. 9. Digital trainer using AND, OR & NOT gates. 10. Digital trainer using NAND gates. 	30

Suggested Evaluation Methods					
Internal Assessment: ➤ Theory 20 Marks • Class Participation: 5 Marks • Seminar/presentation/assignment/quiz/class test etc.: 5 Marks	End Term Examination: 50 Marks				
 Seminar/presentation/assignment/quiz/elass test etc.: 5 Marks Mid-Term Exam: 10 Marks Class Participation: Seminar/Demonstration/Viva-voce/Lab records etc.: 10 Marks Mid-Term Exam: 	20 Marks				
Part C-Learning Resources					
 Recommended Books/e-resources/LMS: Basic Electronics and Linear Circuits by NN Bhargava, D C Kulshresht Integrated Electronics by Millman and Halkias Electronics Devices and Circuit by Allen Mottershead Digital Electronics by R.P. Jain Digital Computer Electronics by Albert Paul Malvino 	ha				

Session: 2023-24							
	Part A - Introduction						
Subject			ELECTRONICS				
Semest	ter		FIRST				
Name	of the Course		Power Devices	and Multivibrato	rs		
Course	e Code		B23-ELE-202				
Course M/DSE	Type: (CC/MCC/M EC/VOC/DSE/PC/AB	DC/CC- EC/VAC)	DSEC-2				
Level o	of the course		100-199				
Pre-req	uisite for the cour	se (if any)	Electronics as a	a Subject (CC-1)			
Course I (CLO):	Learning Outcomes	 After completing this course, the student will be able to: Understand the working of Power Device SCR Understand the working and applications of DIAC, TRIAC & UJT Understand the use and working of Choppers Understand the working and design of multivibrators. Hands-on practice of the power devices and multivibrators based experiments 					
Credit	S	The	eory	Practical	Total		
			3	1	4		
Contae	ct Hours	2	45	30	75		
Max. Marks:100 (70 Theory + 30 Practical)Exam Time: 3 Hours each for ThInternal Assessment Marks:20 Theory + 10 PracticalPracticalEnd Term Exam Marks:50 Theory + 20 PracticalPractical					Hours each for Theory &		
Part B- Contents of the Course							
 Instructions for Paper- Setter Nine questions will be set in all. All questions will carry equal marks. Question No. 1, which will be short answer type covering the entire syllabus, will be compulsory. The remaining eight questions will be set unit wise selecting two questions from each Unit I to IV. The candidate will be required to attempt question No. 1 and four more questions selecting one question from each unit. 							
Unit		Тор	bics		Contact Hours		

Ι	POWER SEMI CONDUCTOR DEVICES-I : Introduction to Thyristors, comparison of Transistors and Thyristors, Thyristors Family, Silicon Controlled Rectifiers (SCR's), Two transistor analogy - Static and Dynamic characteristics - Turn on and turn off methods, Rating and specifications of SCR, Series and Parallel connection of SCR, Applications of SCR	12
II	POWER SEMI CONDUCTOR DEVICES-II: DIAC: Construction, working and Characteristics, TRIAC: Construction, working and Characteristics, Unijunction Transistor: Construction, working and Characteristics, UJT as relaxation oscillators	10
III	POWER SEMI CONDUCTOR DEVICES-III: CHOPPERS: Basic chopper circuit, types of choppers step-down chopper, step-up chopper, operation of D.C. chopper circuits using self-commutation, cathode pulse turn-off chopper, load sensitive cathode pulse turn-off chopper (Jones Chopper), Morgan's chopper	11
IV	Switching Circuits (Multivibrators): Construction and working of: Astable Multivibrator, Monostable Multivibrator, Bistable Multivibrator, Comparison of different Multivibrators, Applications of Multivibrators, Schmitt Trigger (Emitter Coupled Binary) applications of Schmitt Trigger	12
V*	 Note: A candidate is required to perform minimum 6 experiments out of the list provided during course of study in this semester. 1. Characteristics of SCR 2. Characteristics of UJT 3. Characteristics of DIAC 4. Characteristics of TRIAC 5. UJT Relaxation Oscillator 6. Study of Astable multivibrator and plot the waveform 7. Study of Monostable Multivibrator and plot the waveform 8. Study of Bistable Multivibrator and plot the waveform 9. To observe and note down the output waveforms of Schmitt trigger using transistors 10. Study of triagular wave form generator using UJT. 	30
	Suggested Evaluation Methods	
Inter > 1 • • • • • • • • • • • • •	nal Assessment: Theory 20 Marks Class Participation: 5 Marks Seminar/presentation/assignment/quiz/class test etc.: 5 Marks Mid-Term Exam: 10 Marks Practicum 10 Marks Class Participation: Seminar/Demonstration/Viva-voce/Lab records etc.: 10 Marks Mid-Term Exam:	End Term Examination: 50 Marks 20 Marks
	Part C-Learning Resources	

- 1. Power Electronics, M.D.Singh & K.B.Khanchandani, TMH
- 2. Power Electronics, P.C.Sen, TMH
- 3. Power Electronics Circuits, Devices and Applications, 3rd Edition, M.H. Rashid, Pearson Education
- 4. Industrial electronics G.K. Mithal, Khanna Publications Delhi 15thEd.1992.
- 5. Industrial and power electronics C. Harish Raj Umesh Publications 4th Edn. 1992.
- 6. Industrial and Power Electronics by G.K. Mithal
- 7. Integrated Electronics by Millman and Halkias, TMH
- 8. Electronic Devices and Circuits by Sanjeev Gupta, Dhanpat Rai Publicaions

Session: 2023-24					
	Part	A - Introductior	1		
Subject		ELECTRONICS			
Semester		SECOND			
Name of the Course		Basic Electronio	c Components & Devic	es	
Course Code		B23-ELE-203			
Course Type: (CC/MCC/M M/DSEC/VOC/DSE/PC/AI	DC/CC- EC/VAC)	CC-M2			
Level of the course		100-199			
Pre-requisite for the cour	rse (if any)	Physics as a Su	bject at 4.0 Level (Clas	s XII)	
Course Learning Outcomes (CLO):	 After completing this course, the learner will be able to: 1. Learn about active, Passive components and junction diode's 2. Understand the applications of junction diode and Zener diode 3. Understand the Concept of Bipolar Junction Transistor 4. Understand various R, L and C circuits 5. Practical exposure of the different active and passive components in their uses 				
Credits	Th	eory	Practical	Total	
		1	1	2	
Contact Hours]	15	30	45	
Max. Marks: 50 (30 Th Internal Assessment Marks End Term Exam Marks: 20	eory + 20 Prac s: 10 Theory + 0Theory + 15 I	tical) 5 Practical Practical	Exam Time: 3 Hou & Practical	rs each for Theory	
Part B- Contents of the Course					
 Instructions for Paper- Setter Nine questions will be set in all. All questions will carry equal marks. Question No. 1, which will be short answer type covering the entire syllabus, will be compulsory. The remaining eight questions will be set unit wise selecting two questions from each Unit I to IV. The candidate will be required to attempt question No. 1 and four more questions selecting one question from each unit. 					

Unit	Topics	Contact Hours
Ι	Passive Components: Resistors, Capacitors, Inductors, Transformers, Relays, Fuses (their types & applications). Junction Diodes: Rectifying diode, Forward and reverse bias characteristics, Varactor Diode, Light Emitting Diode, Photo diode and Photo transistors (qualitative only).	4
II	Rectifiers: Half wave, Full wave, Bridge, Clipping and Clamping circuits. Zener diode: Zener diode as voltage regulator.	3
III	Bipolar Junction Transistor: Basic working principle, Input and Output Characteristics of CB & CE configurations. Transistor as an amplifier, Transistor as a switch.	4
IV	Sinusoidal Circuit Analysis : for RL, RC and RLC Circuits, Resonance in Series and Parallel RLC Circuits, Frequency Response of Series and Parallel RLC Circuits, Quality (Q) Factor and Bandwidth.	4
V*	 Note: A candidate is required to perform minimum 4 experiments out of the list provided during course of study in this semester. 1. Measurement of resistance value using colour codes and multimeter. 2. To study the V-I characteristics of PN junction diode. 3. To study the zener diode as voltage regulator. 4. To study HWR and measurement of ripple factor without filter. 5. To study FWR and measurement of ripple factor without filter. 6. To study diode as shunt clipping circuit. 7. To study diode as clamping element. 8. Study of CB characteristics. 9. Study of CE characteristics. 10. Measurement of voltage and Time period using CRO. 	30
	Suggested Evaluation Methods	
Intern ≻ T • • •	hal Assessment: Theory 10 Marks Class Participation: 4 Marks Seminar/presentation/assignment/quiz/class test etc.: Mid-Term Exam: 6 Marks racticum 5 Marks Class Participation: Seminar/Demonstration/Viva-voce/Lab records etc.: 5 Marks Mid-Term Exam:	End Term Examination: 20 Marks 15 Marks
-	Part C-Learning Resources	

- 1. Integrated Electronics by Millman and Halkias.
- 2. Basic Electronics and Linear Circuits by NN Bhargava, DC Kulshreshtha (TTTI)
- 3. Electronics Devices and Circuit by Allen Mottershead
- 4. Basic Electronics SOLID STATE by B L Theraja

Session: 2023-24							
	Part A - Introduction						
Subject	Subject						
Semester			SECOND				
Name of	the Course		Understanding	of Mobiles and C	Computer Systems		
Course C	Code		B23-ELE-204				
Course T M/DSEC	ype: (CC/MCC/M /VOC/DSE/PC/AI	DC/CC- EC/VAC)	MDC-2				
Level of t	the course		100-199				
Pre-requisite for the course (if any) B.A. & B.Com. Ist Sem.							
Course Lea (CLO):	arning Outcomes	 After completing this course, the learner will be able to: 1. Identify the different parts of Computer or Laptop systems. 2. Know about various backup systems and cable connections 3. Learn about different printers available 4. Understand the Setting of Internet Connection with computer/Laptop systems 5. Hands-on with the different parts and peripherals of computer 					
Credits		The	eory	Practical	Total		
			2	1	3		
Contact	Hours	3	30	30	60		
Max. Mar Internal A End Term	rks: 75 (50 Theo Assessment Marks: 7 n Exam Marks: 35 T	bry + 25 Practic 15 Theory + 5 I Theory + 20 Pra	eal) Practical actical	Exam Time: 3 Practical	Hours each for Theory &		
Part B- Contents of the Course							
Instructions for Paper- Setter 1. Nine questions will be set in all. All questions will carry equal marks. 2. Question No. 1, which will be short answer type covering the entire syllabus, will be compulsory. The remaining eight questions will be set unit wise selecting two questions from each Unit I to IV. The candidate will be required to attempt question No. 1 and four more questions selecting one question from each unit. 3. Medium of examination may be Hindi/English.							
Unit		Тор	pics		Contact Hours		

Ι	Identification of various parts of Computer/ Laptop, Understanding the computer configuration/Laptop configuration and Mobile Configuration	8
Π	Power Backup: Inverter, UPS, Dry Battery Various Interfacing Cables, connectors and converters for computer, Laptop and Mobile	8
III	Printer Scanner Configuration Projector: Types of Projectors and their Installation	7
IV	Setting Up of Internet Connection: Wired & Wi-fi Setting Up of a complete ICT solution using Computer/laptop and Mobile and interactive Panel	7
V*	 Note: A candidate is required to perform minimum 4 experiments out of the list provided during course of study in this semester. Introduction of Computer Peripherals (input devices, output devices etc) Disassembling computer system. Reassembling computer system Familiarization with Motherboard and its Components. Troubleshooting and Repairing of Keyboard and Scanner. Troubleshooting and Repairing of Printer Troubleshooting and Repairing of Speaker and Web camera. 	30
	Suggested Evaluation Methods	
Intern ≻ T • • • •	hal Assessment: Theory 15 Marks Class Participation: 4 Marks Seminar/presentation/assignment/quiz/class test etc.: 4 Marks Mid-Term Exam: 7 Marks racticum 5 Marks Class Participation: Seminar/Demonstration/Viva-voce/Lab records etc.: 5 Marks Mid-Term Exam: Part C L conving Demonstration	End Term Examination: 35 Marks 20 Marks
	Part U-Learning Kesources	

- 1. Computer Fundamentals by Pradeep K. Sinha BPB Publications
- 2. IBM PC & Clones: Hardware Trouble Shooting and Maintenance by B.Govindarajalu, Tata McGraw Hill
- 3. PC Upgrade & Repair Bible, Wiley India.
- 4. PC Systems, Installation and Maintenance, Second Edition by R. P. Beales,
- 5. PC Upgrade & Repair Black Book by Ron Gilster.
- 6. Computer Installation and Servicing by D Balasubramanian

Session: 2023-24					
	Part	A - Introductior	1		
Subject		ELECTRONICS			
Semester		THIRD			
Name of the Course		Combinational	& Sequential Circuits		
Course Code		B23-ELE-301			
Course Type: (CC/MCC/M M/DSEC/VOC/DSE/PC/AI	DC/CC- EC/VAC)	CC-3 MCC-4			
Level of the course		100-199			
Pre-requisite for the cour	se (if any)	Basic Knowledg	ge of Electronics in B.S	c. Ist Year	
Course Learning Outcomes (CLO):	 After completing this course, the learner will be able to: 1. Understand the Design principle of basic combinational circuit 2. Understand the design and working of different advanced combinational circuits 3. Learn the basic concepts and working of sequential circuits 4. Learn the working and design principle of asynchronous and synchronous counters 5. Use of Combinational and sequential circuits using digital trainer kits 				
Credits	The	eory	Practical	Total	
		3	1	4	
Contact Hours	2	45	30	75	
Max. Marks:100(70 Theory + 30 Practical)Exam Time: 3 Hours each for TheoryInternal Assessment Marks:20 Theory + 10 PracticalPracticalEnd Term Exam Marks:50 Theory + 20 PracticalPractical				rs each for Theory &	
Part B- Contents of the Course					
 Instructions for Paper- Setter Nine questions will be set in all. All questions will carry equal marks. Question No. 1, which will be short answer type covering the entire syllabus, will be compulsory. The remaining eight questions will be set unit wise selecting two questions from each Unit I to IV. The candidate will be required to attempt question No. 1 and four more questions selecting one question from each unit. 					

Unit	Topics	Contact Hours
Ι	Combinational Circuit-I: Design principle of combinational circuit: Half adder, full adder, half subtractor, full subtractor, Railway track switching system, common light switching for a group of flats, Parity Generator.	10
П	Combinational Circuits-II : Multiplexers, Demultiplexer, Decoder, Encoder, Parity bit generator and checker, Code Converter: BCD to Seven Segment, Binary to Gray, Gray to Binary, Binary to Excess-3, Excess-3 to Binary, Application of combinational circuit: adder circuit using Multiplexers, Boolean expression implementation using Multiplexer, Boolean expression implementation using Demultiplexer	12
III	Sequential Circuits : Basic Sequential circuit, Asynchronous and Synchronous circuits, RS FF and JK Flip Flop, Race Around Condition, Master Slave JK flip flop, T and D Flip Flop, Excitation Table, Conversion of Flip Flop, State Diagram.	12
IV	Counters: Asynchronous Binary Counters, Asynchronous Mod-N Counter, Synchronous counter: Design principle of Modulo- N Counters, UP-Down counters, Decade Counter, BCD Counter.	10
V*	 Note: A candidate is required to perform minimum 6 experiments out of the list provided during course of study in this semester. Study of different types of digital IC's: functions, pin diagram, block diagram of 7400, 7402, 7404, 7408, 7432, 7474, 7476, 7490, 74153, 74155 Design a half adder using IC 7400. Design a full adder using two half adders. Study of parity generator/checker. To study a 4:1 Multiplexer. To study and design a Code Converter. To verify the functionality of J-K, D and T Flip-Flops using 7476 and 7474 ICs. To study and design a MOD-N Counter (Synch/Asynch). 	30

Suggested Evaluation Methods				
Internal Assessment: ➤ Theory 20 Marks • Class Participation: 5 Marks • Seminar/presentation/assignment/quiz/class test etc.: 5 Marks • Mid-Term Exam: 10 Marks ➤ Practicum 10 Marks • Class Participation: • Seminar/Demonstration/Viva-voce/Lab records etc.: 10 Marks • Mid-Term Exam:	End Term Examination: 50 Marks 20 Marks			
Part C-Learning Resources				
 Recommended Books/e-resources/LMS: 1. Digital Electronics & Micro computers - R. K. Gaur (4th edition) 2. Modern Digital Electronics - R.P. Jain (4th edition) 3. Digital Principles and Applications by Leach Donald, Malvino AP (6th Edition) 4. Digital fundamentals by R.P. Jain & Floyd. 				

Session: 2023-24					
	Part	A - Introductior	١		
Subject		ELECTRONICS			
Semester		THIRD			
Name of the Course		Digital Electror	iics		
Course Code		B23-ELE-302			
Course Type: (CC/MCC/M M/DSEC/VOC/DSE/PC/AI	DC/CC- EC/VAC)	MCC-5			
Level of the course		100-199			
Pre-requisite for the cour	se (if any)	Basic Knowled	ge of Electronics in B.S	ic. Ist Year	
Course Learning Outcomes (CLO):	 After completing this course, the learner will be able to: 1. Learn the basic concepts of flip flops and working of sequential circuits 2. Learn the design of asynchronous and synchronous counters 3. Understand the concept of shift registers and its applications 4. Understand the logics and theory of the semiconductor memories 5. Use of Combinational and sequential circuits using digital trainer kits 				
Credits	The	eory	Practical	Total	
		3	1	4	
Contact Hours	2	15	30	75	
Max. Marks: 100(70 The Internal Assessment Marks: 2 End Term Exam Marks: 50 T	Max. Marks:100(70 Theory + 30 Practical)Exam Time: 3 Hours each for Theory &Internal Assessment Marks:20 Theory + 10 PracticalPracticalEnd Term Exam Marks:50 Theory + 20 PracticalPractical				
Part B- Contents of the Course					
 Instructions for Paper- Setter Nine questions will be set in all. All questions will carry equal marks. Question No. 1, which will be short answer type covering the entire syllabus, will be compulsory. The remaining eight questions will be set unit wise selecting two questions from each Unit I to IV. The candidate will be required to attempt question No. 1 and four more questions selecting one question from each unit. 					

Unit	Topics	Contact Hours
Ι	Basic Sequential circuit : Asynchronous and Synchronous circuits, RS Flip-Flop, JK Flip Flop, Race Around Condition, Master Slave JK flip flop, T and D Flip Flop, Excitation Table, Conversion of Flip Flop.	11
Π	Counters: Asynchronous Binary Counters, Asynchronous Mod-N Counter, Synchronous counter: Design principle of Modulo-N Counters, UP-Down counters, Decade Counter, skipping state counter.	12
III	Shift Registers : SISO, SIPO, PISO, PIPO, Bidirectional Shift register, Universal Shift register Applications of shift register: Ring counter, Johnson Counter, Time delay generation.	11
IV	Memories: Memory Organization and Operation, Expanding Memory Size, Classification and Characteristics of Memories, Read Only Memory (ROM Organization, Programming Mechanisms, Read and Write Memory (Static and Dynamic), Bipolar RAM Cell, MOS RAMs, Charge Couple Device Memory (Basic concept of CCD, Operation of CCD)	11
V*	Note: A candidate is required to perform minimum 5 experiments out of the list provided during course of study in this semester.	30
	1. Study of JK and T type flip flops using IC 7476.	
	2. Study of D flip flops using IC 7474.	
	3. Design a 4-bit Ripple counter	
	4. Design an asynchronous decade counter	
	5. Design of Up- Down Counter	
	6. Design a Ring counter	
	7. Realization of shift Register using Trainer Kit.	
	8. Realization of Bidirectional shift Registers using	
	Trainer Kits	
	Suggested Evaluation Methods	

Internal Assessment: ➤ Theory 20 Marks • Class Participation: 5 Marks	End Term Examination: 50 Marks			
 Seminar/presentation/assignment/quiz/class test etc.: 5 Marks Mid-Term Exam: 10 Marks Practicum 10 Marks Class Participation: Seminar/Demonstration/Viva-voce/Lab records etc.: 10 Marks Mid-Term Exam: 	20 Marks			
Part C-Learning Resources				
 Recommended Books/e-resources/LMS: Digital Electronics & Micro computers - R. K. Gaur (4th edition) Modern Digital Electronics - R.P. Jain (4th edition) Digital Principles and Applications by Leach Donald, Malvino AP (6th Edition) Digital fundamentals by R.P. Jain & Floyd. 				

Session: 2023-24					
Part A - Introduction					
Subject		ELECTRONICS			
Semester		THIRD			
Name of the Course		Electronics in S	smart World		
Course Code		B23-ELE-303			
Course Type: (CC/MCC/M M/DSEC/VOC/DSE/PC/AI	DC/CC- EC/VAC)	MDC-3			
Level of the course		100-199			
Pre-requisite for the course (if any)		 No Programming language or Experience needed Interest and passion about Automotive Electronics 			
Course Learning Outcomes (CLO):	 ning Outcomes After completing this course, the learner will be able to: 1. understand applications of electronics in smart homes. 2. understand applications of electronics in education sector and agriculture sector. 3. understand applications of electronics in smart homes. 4. understand applications of electronics in smart healthcare. 5. get the insight knowledge by experiential learning 			be able to: t homes. ducation sector and t homes. t healthcare. hing	
Credits	The	eory	Practical	Total	
		2	1	4	
Contact Hours	3	30	30	60	
Max. Marks: 75 (50 Theo Internal Assessment Marks: End Term Exam Marks: 35 T	cal) Exam Time: 3 Hours each for Theory Practical & Practical actical		ours each for Theory		
Part B- Contents of the Course					
 Instructions for Paper- Setter Nine questions will be set in all. All questions will carry equal marks. Question No. 1, which will be short answer type covering the entire syllabus, will be compulsory. The remaining eight questions will be set unit wise selecting two questions from each Unit I to IV. The candidate will be required to attempt question No. 1 and four more questions selecting one question from each unit. 					

Unit	Topics	Contact Hours		
Ι	Evolution of smart homes; Video monitoring, Security and alarms, CCTV;	8		
II	Role of Electronics in Education and Agriculture (Drones for survey, Smart-irrigation);	6		
III	Electronics in Smart watch, Auto-mobiles, ATM. RF-ID cards: Working and applications	11		
IV	Electronics in Healthcare: Digital Thermometers, BP measurement, Digital X-Ray, MRI, USG, ECG (Basic principle only).	11		
V*	 Perform at least two activities and make the report on it: Prepare a project report on proposed features of smart Homes Prepare a PowerPoint presentation on any one electronic instrument used in Health care. Prepare a project report on proposed features of smart City Prepare a report on ATM systems 	30		
	Suggested Evaluation Methods			
Intern ≻ T • • • • • • • • • • • • •	hal Assessment: heory 15 Marks Class Participation: 4 Marks Seminar/presentation/assignment/quiz/class test etc.: 4 larks Mid-Term Exam: 7 Marks racticum 5 Marks Class Participation:	End Term Examination: 35 Marks 20 Marks		
•	Seminar/Demonstration/Viva-voce/Lab records etc.: 5 Marks Mid-Term Exam:			
 	Part C-Learning Resources	1		
 Recommended Books/e-resources/LMS: Ribbens, "Understanding Automotive Electronics", 7th Edition, Elsevier, Indian Reprint, 2013. Tom Denton, "Automotive Electric and Electronic Systems", 3rd Edition, Elsevier, 2004 <u>https://kanchiuniv.ac.in/coursematerials/autotronics.pdf</u> Sensors and Actuators, D. Patranabis, 2nd Ed., PHI, 2013. Make sensors: Terokarvinen, Kemo, Karvinen and Villey Valtokari, 1st edition, maker media, 2014. Sensors Handbook- Sabrie Soloman, 2nd Ed. TMH, 2009 				

Session: 2023-24						
	Part A - Introduction					
Subject		ELECTRONICS				
Semester		FOUR				
Name of the Course		Operational Ar	nplifier & Sinusoidal C	Oscillators		
Course Code		B23-ELE-401				
Course Type: (CC/MCC/M	IDC/CC-	CC-4				
M/DSEC/VOC/DSE/PC/AI	EC/VAC)	MCC-6				
Level of the course		200-299				
Pre-requisite for the course (if any) Basic Knowledge of Electronics in B.Sc. Ist Year			Sc. Ist Year			
Course Learning Outcomes (CLO):	Course Learning Outcomes (CLO):After completing this course, the learner will be able to: 1. Understand the concept and working of operational amplifier. 2. Understand the op-amp parameters and its applications 3. Learn about various amplifiers circuits and negative feedback 4. Understand the concept of positive feedback and working of different oscillators5.Hands-on with various op-amp circuits and oscillators					
Credits	Th	eory	Practical	Total		
		3	1	4		
Contact Hours 4		45	30	75		
Max. Marks:100 (70 Theory + 30 Practical)Exam TInternal Assessment Marks:20 Theory + 10 PracticalPracticalEnd Term Exam Marks:50 Theory + 20 PracticalPractical			Exam Time: 3 Hou Practical	rs each for Theory &		
	Part B- C	ontents of the	Course			
 Nine questions wil Question No. 1, y 	Instruction l be set in all. A which will be	ons for Paper- Il questions will short answer ty	<u>Setter</u> carry equal marks. ype covering the ent	ire syllabus, will be		

Unit	Topics	Contact Hours
Ι	Operational Amplifier- I: Ideal operational amplifier, Op-amp internal circuit (Emitter Coupled Differential amplifier, level translator, output stage), Differential Amplifier, Use of Current Mirror as Constant Current Source, CMRR, Voltage follower, Op-amp as Inverting Amplifier, Non-inverting amplifier.	11
П	Operational Amplifier- II: Practical Op-Amp: Input Offset Voltages, input bias Current, input offset current, thermal drift, effect of error sources, summing amplifier, subtractor, Integrator, Differentiator circuit, Log and Antilog Amplifier, Divider and Multiplier.	11
III	Amplifiers & Feedback: Classification of Amplifiers (voltage, current, Transconductance, Transresistance amplifier), Feedback concept, calculation of transfer gain in degenerative and regenerative feedbacks, Feedback topologies, Effect of negative feedback on gain, Non-linear distortion, Frequency response, Effect of negative voltage shunt feedback on input and output resistance, Effect of negative voltage series feedback on input and output resistance, Effect of negative current shunt feedback on input and output resistance, Effect of negative current series feedback on input and output resistance.	12
IV	Oscillators: Principle of oscillations, condition for sustained oscillation (Barkhausen criterion), stability of oscillator, Principle, working and frequency calculation of RF oscillators (Hartley oscillator, Colpitts oscillator, crystal oscillator) and AF Oscillators (Wien Bridge oscillator, R-C Phase-shift oscillator)	11
V*	 Note: A candidate is required to perform minimum 6 experiments out of the list provided during course of study in this semester. Operational amplifier as Unity gain buffer amplifier. Operational amplifier as an Inverting amplifier and Non- inverting amplifier. Operational amplifier as Summing amplifier. Operational amplifier as Difference amplifier. Operational amplifier. Measurement of offset voltage, bias currents & CMRR of an operational amplifier. Study and design of an integrating circuit using op-amp IC 741. Study and design of a differentiating circuit using op-amp IC 	30

	8. 9. 10. 11.	 741. To study the design of Hartley oscillator & measure its frequency. To study the design of Colpitt's oscillator & measure its frequency. To study the design of Phase shift oscillator & measure its frequency. To study the design of Wein bridge oscillator & measure its frequency. 	
		Suggested Evaluation Methods	
Inter > 7 • • • • • •	nal Ass Theory Class Semin Mid-T Class Semin Mid-T	sessment: 20 Marks Participation: 5 Marks har/presentation/assignment/quiz/class test etc.: 5 Marks "erm Exam: 10 Marks Participation: har/Demonstration/Viva-voce/Lab records etc.: 10 Marks "erm Exam:	End Term Examination: 50 Marks 20 Marks
		Part C-Learning Resources	
Reco 1. 2. 3.	mmen Basic I Opam Electr	ded Books/e-resources/LMS: Electronics Solid state by B.L. Theraja. p and linear circuits by Ramakant A Gayakward. onics for Scientist & Engineers by Vishvanathan & Mehta.	

Session: 2023-24					
Part A - Introduction					
Subject		ELECTRONICS			
Semester		FOUR			
Name of the Course		I C Fabrication	I C Fabrication Technology		
Course Code		B23-ELE-402			
Course Type: (CC/MCC/M M/DSEC/VOC/DSE/PC/AI	DC/CC- EC/VAC)	MCC-7			
Level of the course		200-299	200-299		
Pre-requisite for the course (if any) Basic Knowledge of Electronics in B.Sc. Ist Year			st Year		
Course Learning Outcomes (CLO):	 After completing this course, the learner will be able to: Learn about basic IC Fabrication Processes Understand the concept of Thermal Oxidation, Diffusion and other thin film processes. Learn about various photolithography methods and their applications Learn about various etching methods of different semiconductor substrates. Get the exposure of the field visit to IC Fabrication Laboratory and other hands-on experiences. 				
Credits Theor		eory	Practical	Total	
	3 1		1	4	
Contact Hours	45 30 75				
Max. Marks: 100 (70 Theory + 30 Practi Internal Assessment Marks: 20 Theory + 10 End Term Exam Marks: 50 Theory + 20 Pra		cal) Practical actical	Exam Time: 3 Hours & Practical	ach for Theory &	

Part B- Contents of the Course				
 Instructions for Paper- Setter Nine questions will be set in all. All questions will carry equal marks. Question No. 1, which will be short answer type covering the entire syllabus, will be compulsory. The remaining eight questions will be set unit wise selecting two questions from each Unit I to IV. The candidate will be required to attempt question No. 1 and four more questions selecting one question from each unit. 				
Unit	Topics	Contact Hours		
Ι	Microelectronics processing : Introduction, Clean Room, Basics of Vacuum Science and Technology, Deposition Technique: Thermal evaporation, Sputtering, Chemical Vapor Deposition, PECVD, Metallization, Epitaxy: Introduction, Vapor phase Epitaxy, Liquid phase epitaxy and Molecular beam epitaxy.	11		
Π	Thermal Oxidation of Silicon, Oxide Formation, Properties of Thermal Oxides of Silicon, Uses of Silicon Oxide, Basic diffusion process, Diffusion Equation, Diffusion Profiles, Diffusion in Silicon, Lateral Diffusion, Introduction to Ion Implatation Process, Ion Stopping, Ion Channeling, Disorder and Annealing	12		
III	Photolithography, Negative and Positive Photo resist, Resist Application, Exposure and Development, Photolithographic Process Control. E-Beam Lithography, X-Ray Beam Lithography and Ion Beam Lithography.	11		
IV	Wet Chemical Etching, Chemical Etchants for SiO ₂ , Si ₃ N ₄ , Polycrystalline Silicon and other microelectronic materials, Plasma Etching, Plasma Etchants, Photoresist Removal, Lift off process, Etch Process Control	11		
V*	 Perform at least two activities and make the report on it: 1. Visit a nearest IC Processing lab and prepare a project report/ PPT. 2. Prepare a PowerPoint presentation on any one fabrication process. 3. Simulation of any of the IC fabrication process using open Source tool. 	30		

Suggested Evaluation Methods			
Internal Assessment: ➤ Theory 20 Marks • Class Participation: 5 Marks • Seminar/presentation/assignment/quiz/class test etc.: 5 Marks • Mid-Term Exam: 10 Marks ▶ Practicum 10 Marks • Class Participation: • Seminar/Demonstration/Viva-voce/Lab records etc.: 10 Marks • Mid-Term Exam:	End Term Examination: 50 Marks 20 Marks		
Part C-Learning Resources	·		
Recommended Books/e-resources/LMS:			
 Microelectronic Processing: An Introduction to the Manufacture of Integrated Cir Ruska (McGraw Hill International Edition). VLSI Technology By S.M.Sze (2nd Edition) VLSI Fabrication Principles: Silicon and Gallium Arsenide by Sorab K. Ghandhi (Joh 	rcuits by W. Scot nn Wiley & Sons).		

Session: 2023-24					
Part A - Introduction					
Subject		ELECTRONICS			
Semester		FOUR	FOUR		
Name of the Course		Electronic Com	Electronic Communication		
Course Code		B23-ELE-403			
Course Type: (CC/MCC/MDC/CC- M/DSEC/VOC/DSE/PC/AEC/VAC)MCC-8					
Level of the course		200-299	200-299		
Pre-requisite for the course (if any) Basic R			Basic Knowledge of Electronics in B.Sc. Ist Year		
Course Learning Outcomes (CLO):After completing this course, the learner will be able to: 1. Develop the concept of basics of communication systems 2. Familiar with modulation & demodulation methods 3. Familiar with AM, FM and pulse modulation. 4. Learn the different Digital Modulation Techniques. 5. Get the hands-on practice of different communication techniques and methods					
Credits	Theory Practical Total		Total		
	3		1	4	
Contact Hours	45 30		75		
Max. Marks: 100(70 Theory +30 Practical) Internal Assessment Marks: 20 Theory +10 Practical End Term Exam Marks: 50 Theory +20 Practical		al) Practical ctical	Exam Time: 3 Hour Practical	rs each for Theory &	
Part B- Contents of the Course					
Instructions for Paper- Setter 1. Nine questions will be set in all. All questions will carry equal marks. 2. Oraction Number of the which will be what any equation of the write any equation of the set of the					

2. Question No. 1, which will be short answer type covering the entire syllabus, will be compulsory. The remaining eight questions will be set unit wise selecting two questions from each Unit I to IV. The candidate will be required to attempt question No. 1 and four more questions selecting one question from each unit.

Unit	Topics	Contact Hours			
I	Communication Systems: Elements of Communication Systems, Basic Terminology in communication system, Bandwidth of Signal, Bandwidth of Transmission medium, Propagation of Electromagnetic waves: Ground Wave, Sky wave, Space Wave	11			
П	Modulation & Demodulation : Principle of modulation , Amplitude Modulation ,Percent Modulation ,upper & lower side frequencies ,upper & lower side bands, mathematical analysis of a modulated carrier wave, power relations in an AM wave, simple idea about different forms of amplitude modulation. A) DSB-SC B) SSB-TC C) SSBSC	12			
III	Frequency Modulation: Frequency modulation , FM Sidebands, modulation index and number of side bands, mathematical expression for FM wave, Demodulation, diode detector for AM signals.FM detector , Limited and phase shift detectors, comparison between AM & FM.	12			
IV	Pulse Analog Modulation: Channel capacity, Sampling theorem, PAM, PWM, PPM modulation and detection techniques, Multiplexing: TDM and FDM.	10			
V*	 Note: A candidate is required to perform minimum 6 experiments out of the list provided during course of study in this semester: Study of Amplitude Modulation, plot the waveform and calculation of modulation index (using Kit) Study of Amplitude demodulation and plot the waveform (using Kit) Study of Frequency Modulation. Wave form tracing (using Kit). Study of Pulse Amplitude Modulation using IC 555 (using Kit). Study of Pulse Position Modulation using IC 555 (using Kit). Multiplexing Techniques: FDM Multiplexing Techniques: TDM 	30			
	Suggested Evaluation Methods				

Internal Assessment:	End Term
≻ Theory 20 Marks	Examination:
Class Participation: 5 Marks	50 Marks
• Seminar/presentation/assignment/quiz/class test etc.: 5 Marks	
• Mid-Term Exam: 10 Marks	
➢ Practicum 10 Marks	20 Martra
Class Participation:	20 IVIAIKS
• Seminar/Demonstration/Viva-voce/Lab records etc.: 10 Marks	
• Mid-Term Exam:	
Part C-Learning Resources	
Recommended Books/e-resources/LMS:	
1. Kennedy, George & Davis, Bernard "Electronic Communication Syst	ems" Tata McGraw-
Hill 4thEd.	
2. Modem Analog & Digital Communication Systems: B.P. Lathi; Oxford	Univ. Press.
3. Communication Systems S. Haykin, John Willy & Sons.	
4. Taub, Herbert & Schilling, Donald L. "Communication Systems" Tata N	McGraw-Hill
5. Electronic Communication Systems: Fundamentals through Advan	ced (4 th ed.) Wayne
Tomasi, Prentice Hall	-
6. Radio Engineering by G K Mithal	

Session: 2023-24					
	P	art A - Introduc	tion		
Subject		ELECTRONICS			
Semester		FOUR	FOUR		
Name of the Course		Optical Fiber			
		Communicatio	n		
Course Code		B23-ELE-404			
Course Type: (CC/MCC/MDC/CC- M/DSEC/VOC/DSE/PC/AEC/VAC)		DSE-1	DSE-1		
Level of the course	200-299				
Pre-requisite for the cour	se (if any)	Basic Knowledge of Electronics in B.Sc. Ist Year			
Course Learning Outcomes (CLO): After completing this course, the learner will be able to: Understand the basics of Optical Fibers Learn the characteristics of optical fibers and sources and detectors o optical fibers Learn about different couplers and connectors use in optical fiber Understand various analog and digital link Practice of various optical fiber communication techniques 				and detectors of ical fiber ies	
Credits	The	eory	Practical	Total	
		3	1	4	
Contact Hours	45		30	75	
Max. Marks: 100(70 Theory +30 Practical Internal Assessment Marks: 20 Theory +10 Pr End Term Exam Marks: 50 Theory +20 Practi		cal) Practical ctical	Exam Time: 3 Hours each for 7 Practical	Гheory &	
	Part B	- Contents of	the Course		
1. Nine questions will be set in	Instruation	ns will carry equ	er- Setter al marks.	1 71	

2.Question No. 1, which will be short answer type covering the entire syllabus, will be compulsory. The remaining eight questions will be set unit wise selecting two questions from each Unit I to IV. The candidate will be required to attempt question No. 1 and four more questions selecting one question from each unit.

Unit	Topics	Contact Hours
Ι	OVERVIEW OF OPTICAL FIBER COMMUNICATION: Introduction, Historical development, general system, advantages, disadvantages, and applications of optical fiber communication, optical fiber waveguides, Ray theory, cylindrical fiber, single mode fiber, cutoff wave length, mode filed diameter. Optical Fibers: fiber materials, photonic crystal, fiber optic cables specialty fiber.	12
Π	 TRANSMISSION CHARACTERISTICS OF OPTICAL FIBERS: Introduction, Attenuation, absorption, scattering losses, bending loss, dispersion, Intra modal dispersion, Inter modal dispersion OPTICAL SOURCES AND DETECTORS: Introduction, LED's, LASER diodes, Photo detectors, Photo detector noise, Response time, double hetero junction structure, Photo diodes, comparison of photo detectors 	12
III	FIBER COUPLERS AND CONNECTORS : Introduction, fiber alignment and joint loss, single mode fiber joints, fiber splices, fiber connectors and fiber couplers. OPTICAL RECEIVER: Introduction, Optical Receiver Operation, receiver sensitivity, quantum limit, eye diagrams, coherent detection, burst mode receiver operation, Analog receivers.	11
IV	ANALOG AND DIGITAL LINKS: Analog links – Introduction, overview of analog links, CNR, multichannel transmission techniques, RF over fiber, key link parameters, Radio over fiber links, microwave photonics. Digital links – Introduction, point-to-point links, System considerations, link power budget, resistive budget, short wave length band, transmission distance for single mode fibers, Power penalties, nodal noise and chirping	10
V*	 Note: A candidate is required to perform minimum 6 experiments out of the list provided during course of study in this semester: 1. To establish analog link using Optical Fiber. 2. To establish voice link using optical fiber. 3. To Transmit and receive Pulse Amplitude Modulated (PAM) signal 4. To measure Propagation loss in optical fiber 5. To measure bending loss in optical fiber 6. To measure numerical aperture of optical fiber 7. To study splicing & connectors. 8. Study of I-V Characteristics of Fiber optic LED and Photodetector 	30

Suggested Evaluation Methods		
Internal Assessment: ➤ Theory 20 Marks • Class Participation: 5 Marks • Seminar/presentation/assignment/quiz/class test etc.: 5 Marks • Mid-Term Exam: 10 Marks	End Term Examination: 50 Marks	
 Practicum 10 Marks Class Participation: Seminar/Demonstration/Viva-voce/Lab records etc.: 10 Marks Mid-Term Exam: 	20 Marks	
Part C-Learning Resources		
 Recommended Books/e-resources/LMS: 1. Optical Fiber Communication – Gerd Keiser, 4th Ed., MGH, 2008. 2. Optical Fiber Communications– – John M. Senior, Pearson Education. 3 rd Impression 3. Fiber optic communication – Joseph C Palais: 4th Edition, Pearson Education. 	n, 2007.	

Session: 2023-24					
	Part	A - Introduction	ı		
Subject		ELECTRONICS			
Semester		FOUR			
Name of the Course		Wireless and N	Nobile Communication		
Course Code		B23-ELE-405	B23-ELE-405		
Course Type: (CC/MCC/M M/DSEC/VOC/DSE/PC/AI	DC/CC- EC/VAC)	DSE-1			
Level of the course	Level of the course		200-299		
Pre-requisite for the cour	quisite for the course (if any) Basic Knowledge of Electronics in B.Sc. Ist Yea		. Ist Year		
 Course Learning Outcomes (CLO): After completing this course, the learner will be able: To understand the evolution of wireless communication system To inculcate the skill of the link budget design of cellular system. To understand the effects of small scale fading and large scale path loss. To learn the modulation and multiple access techniques used for cellular systems. To Practice of wireless and mobile communication technologies on trainer kit 			ıble: nunication system n of cellular g and large scale echniques used for eation technologies		
Credits	Th	eory	Practical	Total	
	3 1 4		4		
Contact Hours	45		30	75	
Max. Marks: 100(70 Theory +30 Practical) Internal Assessment Marks: 20 Theory +10 Practical End Term Exam Marks: 50 Theory +20 Practical		Exam Time: 3 Hours Practical	each for Theory &		
	Part B- C	ontents of the	Course		
1.Nine questions will be set in a	Instruction all. All question	ons for Paper- ns will carry equ	<u>Setter</u> al marks.	he commute one. The	

2.Question No. 1, which will be short answer type covering the entire syllabus, will be compulsory. The remaining eight questions will be set unit wise selecting two questions from each Unit I to IV. The candidate will be required to attempt question No. 1 and four more questions selecting one question from

each unit.				
Unit	Topics	Contact Hours		
Ι	Introduction to Wireless Communication Systems : Evolution, Mobile Systems around the World, Example of the mobile radio systems, Recent trends, 2G, 3G, 4G and 5G Cellular networks.	10		
	The Cellular Concept: Frequency reuse, Channel assignment, Hand off process, Types of Interference, Cellular capacity			
II	Mobile Radio Propagation:	12		
	Path loss, Radio wave propagation, Reflection, Diffraction, Scattering, Link budget Design, Outdoor and indoor propagation models			
	Principle of multi path propagation: impulse response model of channels, parameters for mobile multi path channels, concept of fading, Rayleigh and Rician fading, Simulation of fading channels.			
III	Modulations techniques for mobile communication: Pulse shaping, Linear and non-linear Modulation techniques, constant envelop modulation, QPSK, MSK, GMSK. Spread spectrum modulation techniques - Direct sequence and Frequency Hopping Spread Spectrum and their applications Equalization, Diversity and Channel coding: Fundamentals of equalization, General adaptive equalizer, Linear and non-linear equalizers, diversity techniques. RAKE receivers, Basic concept of coding.	12		
IV	Multiple access techniques:	11		
.,	Introduction, FDMA, TDMA, CDMA, SDMA, capacity of cellular systems Introduction to Multicarrier systems:			
	OFDM and wireless LAN, WiMAX, GSM, WCDMA, 3GPP LTE and other 4G standards.			
V*	Note: A candidate is required to perform minimum 6 experiments out of the list provided during course of study in this semester:	30		
	 Study of wireless Communications using Communication Trainer Kits : 1. Baseband Communication 2. Adaptive Linear Equalizer 3. Code Division Multiple Access (CDMA) - Multipath 4. Code Division Multiple Access (CDMA) – Multiuser 5. Study of TDMA Trainer Kit 6. Study of FDMA Trainer kit 7. Global System for Mobile Communication (GSM) Trainer Kit 8. Study of QPSK Trainer Kit 9. Study of GMSK Trainer Kit 			
Suggested Evaluation Methods				

Internal Assessment: ➤ Theory 20 Marks • Class Participation: 5 Marks	End Term Examination: 50 Marks		
 Seminar/presentation/assignment/quiz/class test etc.: 5 Marks Mid-Term Exam: 10 Marks Practicum 10 Marks Class Participation: Seminar/Demonstration/Viva-voce/Lab records etc.: 10 Marks Mid-Term Exam: 	20 Marks		
Part C-Learning Resources			
Recommended Books/e-resources/LMS:			
 T.S. Rappaport, "Wireless Communications – Principles and Practice", Prentice Hall of India Pearson Education India, 2002. Andrea Goldsmith, "Wireless Communication", Cambridge University Press, 2005 W C Y Lee, "Mobile Communication Engineering", Tata McGraw Hill, India, 2008 G. Stuber, Principles of Mobile Communication, Springer, 2001 Frenzel, "Communication Electronics", Tata McGraw Hill <u>William C. Y. Lee</u>, "Wireless and Cellular Communications", Third Edition, , TMH 			

ANNEXURE-I

Levels of Courses

Levels of Courses: Courses shall be coded based on the learning outcomes, level of difficulty, and academic rigor. The coding structure is as follows:

0-99: Pre-requisite courses required to undertake an introductory course which will be a pass or fail course with no credits. It will replace the existing informal way of offering bridge courses that are conducted in some of the colleges/ universities.

100-199: Foundation or introductory courses that are intended for students to gain an understanding and basic knowledge about the subjects and help decide the subject or discipline of interest. These courses may also be prerequisites for courses in the major subject. These courses generally would focus on foundational theories, concepts, perspectives, principles, methods, and procedures of critical thinking in order to provide a broad basis for taking up more advanced courses. These courses seek to equip students with the general education needed for advanced study, expose students to the breadth of different fields of study; provide a foundation for specialized higher-level coursework; acquaint students with the breadth of (inter) disciplinary fields in the arts, humanities, social sciences, and natural sciences, and to the historical and contemporary assumptions and practices of vocational or professional fields; and to lay the foundation for higher level coursework.

200-299: Intermediate-level courses including subject-specific courses intended to meet the credit requirements for minor or major areas of learning. These courses can be part of a major and can be pre-requisite courses for advanced-level major courses.

300-399: Higher-level courses which are required for majoring in a disciplinary/interdisciplinary area of study for the award of a degree.

400-499: Advanced courses which would include lecture courses with practicum, seminar-based course, term papers, research methodology, advanced laboratory experiments/software training, research projects, hands-on-training, internship/apprenticeship projects at the undergraduate level or First year Postgraduate theoretical and practical courses.

500-599: Courses at first-year Master's degree level for a 2-year Master's degree programme

600-699: Courses for second-year of 2-year Master's or 1-year Master's degree programme

700 -799 & above: Courses limited to doctoral students